

Silicon Carbide Schottky Barrier Diode

VRRM	1200 V	I _F	2 x 15 A
V _{F(Typ.)}	1.5 V	Qc	72 nC

Features

- Temperature Independent Switching Behavior
- High Surge Current Capability
- Low Conduction Loss
- Zero Reverse Recovery
- High junction temperature 175 °C
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard
- AEC-Q101 qualified

Mechanical Data

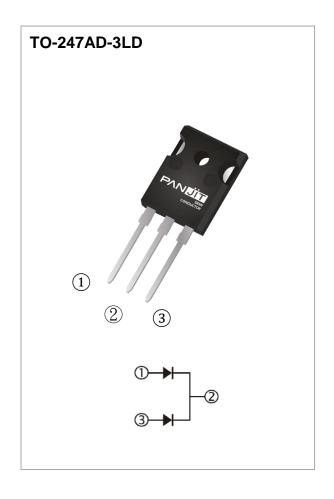
• Case: TO-247AD-3LD molded plastic

• Terminals: Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 6.231 grams

Application

• PFC, UPS, PV Inverter, EV Charging Station, Welder



Maximum Ratings and Thermal Characteristics (Tc = 25 °C unless otherwise specified)

PARAMETE	R	SYMBOL	LIMIT	UNITS
Repetitive Peak Reverse Voltage		V_{RRM}	1200	V
DC Blocking Voltage		V _{DC}	1200	V
Continuous Forward Current (Per Leg/Device)	T _C = 155 °C	l _F	15 / 30	А
Repetitive Peak Surge Current Half Sine Wave, D=0.1 (Per Leg)	$T_{C}=25^{\circ}\text{C}$, $t_{p}=10\text{ms}$ $T_{C}=125^{\circ}\text{C}$, $t_{p}=10\text{ms}$	IFRM	92 72	А
Peak Forward Surge Current Half Sine Wave (Per Leg)	T_{C} = 25 °C , t_{p} =10ms T_{C} =125 °C , t_{p} =10ms		104 92	А
Peak Forward Surge Current t _p =10us, Pulse (Per Leg)		IFSM	720	А
Maximum Power Dissipation (Per Leg	P _{total}	230.8	W	
Operating Junction Temperature Range	TJ	-55~175	°C	
Storage Temperature Range	Tstg	-55~175	°C	



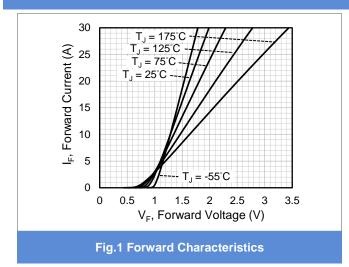
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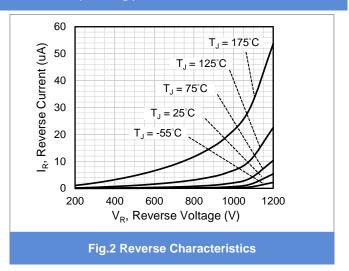
Electrical Characteristics (Per Leg) (T_C = 25 °C unless otherwise specified)

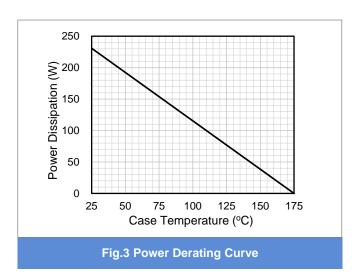
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
- IV # - D	VF	I _F = 15 A, T _J = 25 °C		1.5	1.7	
Forward Voltage Drop		I _F = 15 A, T _J = 175 °C	-	2.0	-	V
Reverse Leakage Current	I _R	V _R = 1200 V, T _J = 25 °C	1	5.3	140	μA
		V _R = 1200 V, T _J = 175 °C	ı	0.05	1	mA
Total Capacitive Charge	Qc	I _F = 15 A, V _R = 800V	ı	72	1	nC
Total Capacitance	O	V _R = 1V, f = 1MHz	ı	784	ı	pF
		V _R = 400V, f = 1MHz	ı	69.3	ı	pF
		V _R = 800V, f = 1MHz	-	50.2	-	pF
Capacitance Stored Energy	Ec	V _R = 800V	ı	21	-	μJ
Thermal Resistance	Rejc		-	0.65	-	°C/W

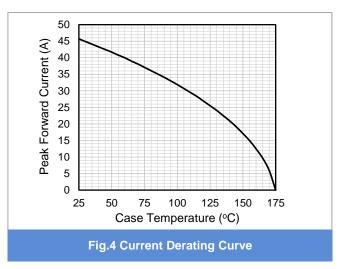
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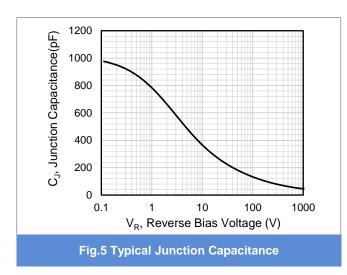
TYPICAL CHARACTERISTIC CURVES (Per Leg)

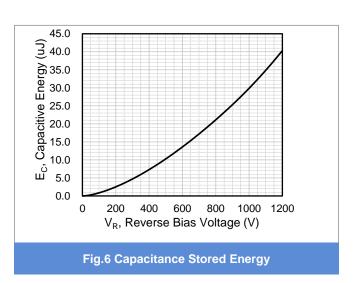










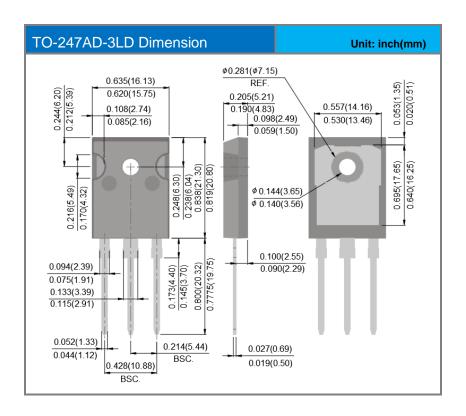




Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PCDH30120CCG1-AU	TO-247AD-3LD	30pcs / Tube	CDH30120CCG1

Packaging Information



PAN JIT SEMI CONDUCTOR

PCDH30120CCG1-AU

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